Diode Semiconductor Device - Page 1 of 1



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Inclosure	e Material:
Glass	
Overall L	ength:
0.380 incl	hes
Terminal	Length:
1.000 incl	hes
Overall D	Diameter:
0.200 incl	hes
Mounting	g Method:
Terminal	
Features	Provided:
Hermetica	ally sealed case
Semicon	ductor Material:
Silicon	
Voltage F	Rating In Volts Per Characteristic:
24.0 reve	erse voltage, peak
Current F	Rating Per Characteristic:
2000.00 r	nicroamperes forward current, average peak
Maximun	n Operating Tempurature Per Measurement Point:
150.0 deg	grees celsius ambient air
Precious	Material And Location:
Terminal	surface silver
Precious	Material:
Silver	
Terminal	Type And Quantity:
2 uninsula	ated wire lead
Shelf Life	9:
N/a	
Unit Of N	leasure:
Demilitar	ization:
No	
Fiig:	
A110a0	